Unit: mm

TOSHIBA GTR Module Silicon N Channel IGBT

# **MP6750**

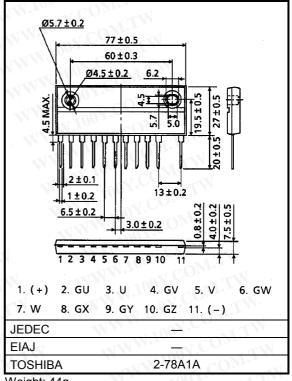
### **High Power Switching Applications Motor Control Applications**

- The electrodes are isolated from case.
- 6 IGBTs are built into 1 package.
- Enhancement-mode
- Low saturation voltage

 $V_{CE (sat)} = 4.0 V (Max) (I_{C} = 15A)$ 

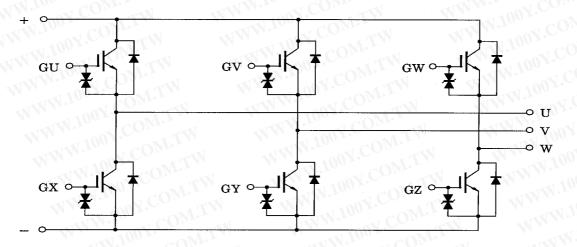
High speed :  $t_f = 0.35 \mu s \text{ (Max) (IC} = 15 \text{A)}$  $t_{rr} = 0.15 \mu s \text{ (Max) (IF} = 15 \text{A)}$ 

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Weight: 44g

### **Equivalent Circuit**



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#### Maximum Ratings (Ta = 25°C)

Chara	acteristic	Symbol	Rating	Unit	
Collector-emitter voltage  Gate-emitter voltage		V <sub>CES</sub>	600	A C	
		V <sub>GES</sub>	± 20		
Collector current	DC	Ic	15	100 x.	
	1ms	I <sub>CP</sub>	30	N 100 Y	
Forward current	DC	IF	15	100	
	1ms	I <sub>FM</sub>	30	A A	
Collector power dissipation (Tc = 25°C)		COPC	55	W	
Junction temperature		$CG_j$	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 ~ 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 minute)	V	
Screw torque		CO.	1.5	N·m	

## WWW.10 Electrical Characteristics (Ta = 25°C)

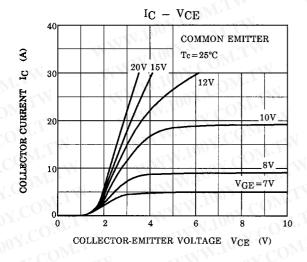
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ± 20V, V <sub>CE</sub> = 0	1 ±00	-1 CC	± 20	μA
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 600V, V <sub>GE</sub> = 0	W. 1	07-0	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	I <sub>C</sub> = 15mA, V <sub>CE</sub> = 5V	3.0	007.0	6.0	٧
Collector-emitter sa	turation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 15A, V <sub>GE</sub> = 15V	MM.	3.0	4.0	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MH	z –	1000	Co	pF
Switching time	Rise time	t <sub>r</sub>	TOON COMP.	(VZ)	0.3	0.6	TI
	Turn-on time	ton	$15V_{\square}$ $150\Omega$	200	0.4	0.8	μs
	Fall time	t <sub>f</sub>	0 LI_15V 30	ov	0.2	0.35	ωμs cOM
	Turn-off time	t <sub>off</sub>		_4	0.5	1.0	COI
Forward voltage	OOY.CO	V <sub>F</sub>	I <sub>F</sub> = 15A, V <sub>GE</sub> = 0	N	1.7	2.5	V
Reverse recovery ti	me OY COM T	t <sub>rr</sub>	I <sub>F</sub> = 15A, V <sub>GE</sub> = -10V di / dt = 50A / µs	LA -	0.08	0.15	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor		4	2.27	°C/W
			Diode	1.TV -	_//	3.09	

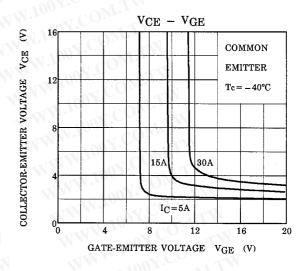
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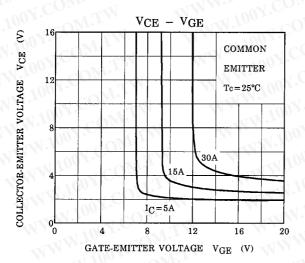
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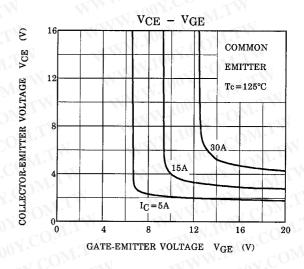
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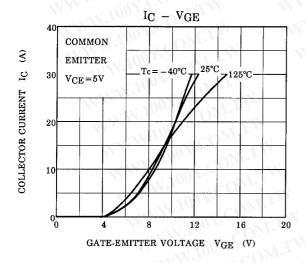
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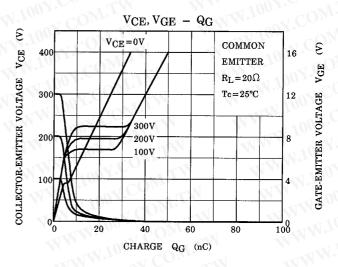






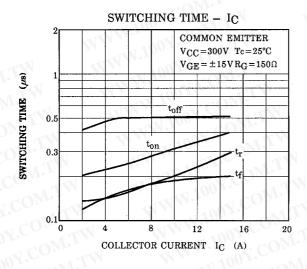


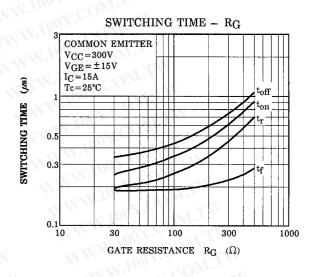


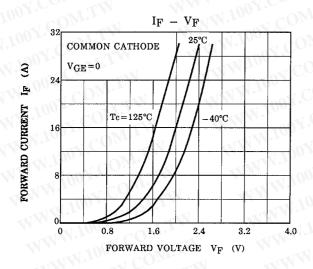


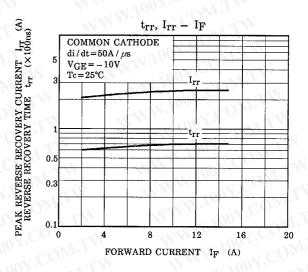
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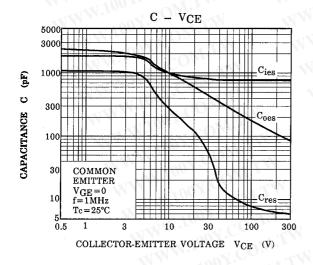
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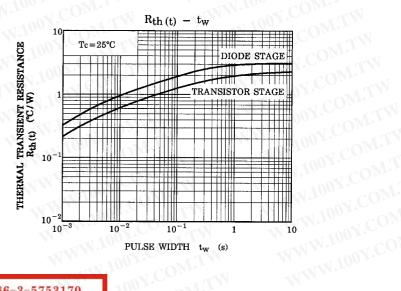








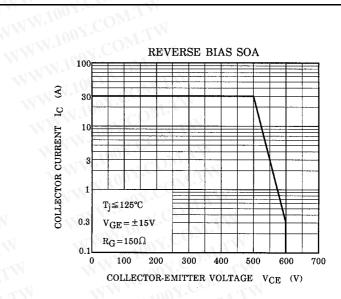




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